Dual Operational Amplifier





КБ1040УД1-4/МВМ (LM358nd2)

DESCRIPTION

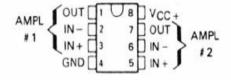
The LM358 consists of two independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, dc gain blocks and all the conventional op amp circuits.

FEATURES

- Wide range of supply voltages
- Low supply current drain independent of supply voltage
- Low input biasing current
- · Low input offset voltage and offset current
- Input common-mode voltage range includes ground
- · Differential input voltage range equal to the power supply voltage
- DC voltage gain 100 V/ mV Typ
- Internally frequency compensation

PACKAGE INFORMATION



ELECTRICAL CHARACTERISTICS

at specified free-air temperature, Vcc = 5 V (unless otherwise noted)

PARAMETER	TEST CONDITIONS*		LM358/ LM358M/ LM358MMK			
			MIN	TYP	MAX	UNIT
Vio	Vcc = 5 V to MAX,	25 °C		3	7	mV
Input offset voltage	V _{IC} = V _{ICR} min, Vo=1.4 V	Full range			9	
xV _{IO} Average temperature coefficient of nput offset voltage		Full range		7		μV/°C
10	Vo=1.4 V	25 °C		2	50	nA
Input offset current		Full range			150	1
αΙΙΟ		Full range		10	1	pA/°C
Average temperature coefficient of input offset current				13*45		•
IB	Vo=1.4 V	25 °C		-20	-250	nA
Input bias current		Full range			-500	
V _{ICR}	Vcc = 5 V to MAX	25° C	0 to Vcc-1.5			V
Common-mode input voltage range	- 104484 - 11104484 155-155-155-150515	Full range	0 to Vcc - 2			
V _{он} High-level output voltage	RL ≥2 κΩ (Note 1)	25 °C	Vcc-1.5			V
	$Vcc = MAX, R_L=2 kΩ$	Full range	26	1	-	
	Vcc = MAX, R _L ≥ 10 kΩ	Full range	27	28		
V _{oL} Low-level output voltage	$R_L \ge 10 \text{ k}\Omega$	Full range		5	20	mV
A _{VD} Large-signal differential	Vcc = 15 V, Vo=1V to 11 V,	25 °C	25	100		V/mV
voltage amplification	$R_L \ge 2 k\Omega$	Full range	15	×		
CMRR Common-mode rejection ratio	Vcc = 5 V to MAX, V _{IC} = V _{ICR} min	25 °C	65	80	b/	dB
k _{SVR} Supply voltage rejection ratio (ΔVcc/ΔV _{IO})	Vcc = 5 V to MAX	25 °C	65	100		dB
Vo1 /Vo2 Crosstalk attenuation	f=1 kHz to 20 kHz	25 °C		120	8%	dB
lo	Vcc = 15 V,	25 °C	-20	-30		mA
Output current	$V_{1D}=1 \ V, V_{0}=0$	Full range	-10			1
	Vcc = 15 V,	25 °C	10	20		
	V _{ID} = - 1 V, Vo = 15 V	Full range	5	74		
	V _{ID} = - 1 V, Vo =200 mV	25 °C	12	30		μА
los Short-circuit output current	Vcc at 5 V, GND at -5 V,Vo=0	25 °C	Ţ:	±40	±60	mA
I _{cc}	Vo - 2.5 V, No load	Full range		0.7	1.2	mA
Supply current (two amplifiers)	Vcc = MAX, Vo = 0.5Vcc, No load	Full range		1	2	

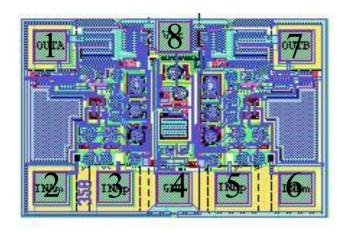
 All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. "MAX" V_{CC} for testing purposes is 30 V. Full range is 0 °C to 70 °C.
Note1 Only for LM358





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Pad Location



Wafer Thickness: 460±30µm (or 350±30µm,

280±30µm) Top metal: AlSi

Backside metal: - (or Ti-Ni (V)-Ag)

Wafer size: 100 mm

Chip size: 0,93 x 0,67 mm

PAD LOCATION COORDINATES

Pad	Pad	Pad size	Coordinates, µm	
N	Name	(µт х µт		
			X	Y
1	1 OUT	88 x 88	120	550
2	1 IN -	88 x 88	120	120
3	1 IN +	88 x 88	300	120
4 GND		88 x 88 465 1	20	
5	2 IN +	88 x 88	630	120
6	2 IN -	88 x 88	810	120
7	2 OUT	88 x 88	810	550
8 V _{cc}		88 x 88	465	565